

L Number	Hits	Search Text	DB	Time stamp
1	32843	flash near2 memor\$3	USPAT; US-PGPUB; JPO	2003/06/04 11:47
2	53181	nand or nand-\$5	USPAT; US-PGPUB; JPO	2003/06/04 11:48
3	1118	(flash near2 memor\$3) same (nand or nand-\$5)	USPAT; US-PGPUB; JPO	2003/06/04 11:48
4	963120	semiconduct\$3 or silicon	USPAT; US-PGPUB; JPO	2003/06/04 11:48
5	973	((flash near2 memor\$3) same (nand or nand-\$5)) and (semiconduct\$3 or silicon)	USPAT; US-PGPUB; JPO	2003/06/04 11:48
6	132416	implant\$3	USPAT; US-PGPUB; JPO	2003/06/04 11:48
7	38453	wordline\$1 or (word adj line\$1)	USPAT; US-PGPUB; JPO	2003/06/04 11:49
8	167805	(insulat\$3 or dielectric) with (hole\$1 or via\$1 or opening\$1)	USPAT; US-PGPUB; JPO	2003/06/04 11:50
9	49310	common near5 source\$1	USPAT; US-PGPUB; JPO	2003/06/04 11:50
10	113	((((flash near2 memor\$3) same (nand or nand-\$5)) and (semiconduct\$3 or silicon)) and (wordline\$1 or (word adj line\$1)) and ((insulat\$3 or dielectric) with (hole\$1 or via\$1 or opening\$1)) and (common near5 source\$1))	USPAT; US-PGPUB; JPO	2003/06/04 11:51
11	50	implant\$3 and (((flash near2 memor\$3) same (nand or nand-\$5)) and (semiconduct\$3 or silicon)) and (wordline\$1 or (word adj line\$1)) and ((insulat\$3 or dielectric) with (hole\$1 or via\$1 or opening\$1)) and (common near5 source\$1))	USPAT; US-PGPUB; JPO	2003/06/04 11:51
12	63	(((((flash near2 memor\$3) same (nand or nand-\$5)) and (semiconduct\$3 or silicon)) and (wordline\$1 or (word adj line\$1)) and ((insulat\$3 or dielectric) with (hole\$1 or via\$1 or opening\$1)) and (common near5 source\$1)) not (implant\$3 and (((flash near2 memor\$3) same (nand or nand-\$5)) and (semiconduct\$3 or silicon)) and (wordline\$1 or (word adj line\$1)) and ((insulat\$3 or dielectric) with (hole\$1 or via\$1 or opening\$1)) and (common near5 source\$1))))	USPAT; US-PGPUB; JPO	2003/06/04 11:51